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IC-SPECIFICATION

TDA 4362 X

Differences to the last edition

Last Edition: DOK-Nr. V66047-S1603-C200-G1 date: 11.12.97

Page 11: #P7: Test values and units changed #P8: Test values and units changed

#P11: Test values changed, wrong values in previous version

Page 12: #P21,22: Min max values added

#P23: Load resistor added and values changed

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AM- Updown - Conversion

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This specification replaces the previous editions

DOK-Nr.	date	DOK-Nr.	date
V66047-S1603-C200-G1	11.12.97		

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TDA 4362 X

Functional Description, Application

Dual-Conversion-AM-Receiver

The TDA 4362 X is an integrated Dual-Conversion- AM-Receiver for use in car radios.

The input signal passes a linear mixer for conversion into the 1.IF (~10 MHz). Via an external bandpass-filter (CER-filter, quartz filter) the 1. IF is converted in a second linear mixer to the 2. IF (~450kHz).

After an external narrowband-selectivity (CER-filter) the 2. IF passes an automatic gain controlled amplifier and is then demodulated to the AF.

Features

- · High flexibility with an external preamplifier stage
- Symmetrical or asymmetrical mixer input
- 2-Pin-Oscillator for the 1. LO
- 1. LO with LC-tank circuit
- 1. LO in 60 to 160 MHz range
- Low narrow band noise
- Divider for 1. LO by 6, 10
- Integrated AGC generation for the prestages
- Strictly symmetrical RF path
- Decoupled direct and divided counter outputs
- 2. LO with external source input
- · Output for gain controlled 2. IF

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Circuit Description

The integrated circuit includes a 2-Pin oscillator (1.LO) with sym. input, buffered output and a double balanced mixer with symmetrical input. This stage converts the AM-Inputsignal to a 1. IF, which is much higher (~10 MHz) than the input frequencies. The 1. LO operates as a LC-varactor tuned oscillator in the same 100 MHz range like the FM-Tuner oscillator (e.g. TUA 4310 X) . So the same peripherial elements can be used.

Depending on the signal strength the prestage AGC controls a MOSFET-prestage amplifier.

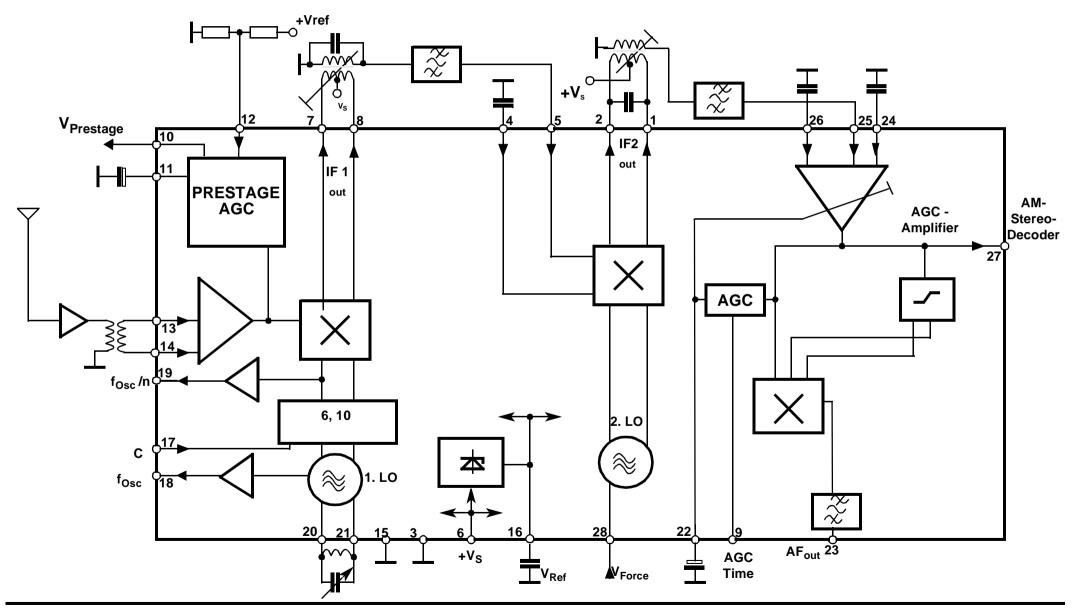
- The 1. IF passes an external selectivity and is then converted in a symmetrical double balanced mixer to the 2. IF.
- The 2. LO operates as an amplifier for an external forcing signal.
- The 2. IF signal passes an automatic gain controlled IF amplifier and is then demodulated to the AF in a quasisynchronous-demodulator.

For AM-Stereo application a gain controlled output of the 2. IF is available.

The TDA 4362 X is prepared to work with a PLL in the 100MHz range. When applied with a standard AM-PLL the oscillator frequency divided by 6 or 10 has to be used. In this case a higher phase noise is to be expected.

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Block Diagram



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Pin Assignment

Pin configuration

- 1. 2. Mixer output
- 2. 2. Mixer output
- 3. Ground (LF)
- 4. 2. Mixer input
- 5. 2. Mixer input
- 6. Supply voltage
- 7. 1. Mixer output
- 8. 1. Mixer output
- 9. AGC-time constant switch
- 10. Prestage voltage output
- 11. Prestage time constant
- 12. Prestage threshold
- 13. Mixer 1 input
- 14. Mixer 1 input
- 15. Ground
- 16. Reference voltage (RF)
- 17. Counter ratio C
- 18. Counter output direct
- 19. Counter output divided
- 20. Local oscillator
- 21. Local oscillator
- 22. LIF time constant
- 23. AF output
- 24. LIF input (blocked to LF GND)
- 25. LIF input active
- 26. LIF input (blocked to LF GND)
- 27. AM output
- 28. 2. LO force input

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Pin Description

Pin 1,2: Open collector output of mixer 2 for the lower IF (~450 kHz)

Pin 3: GROUND: All LF blocking capacitors should be connected to this point.

Pin 4,5: Sym. mixer 2 input for the upper IF (~10.7 MHz). Asym. operation is possible.

The input signal is converted to the lower IF corresponding the equation

 $f_{LIF} = f_{UIF} - f_{2,LO}$

Pin 6: Supply-voltage. This point is to be blocked to ground for AF and for RF-Signals

Pin 7,8: Sym collector output of the mixer 1. The external tank circuit is tuned to the

upper IF.

Pin 9: DC-Voltage determines the AGC-Time. GND: normal mode Vref: fast mode

Pin 10: Buffered prestage AGC output

Pin 11: Blocking capacitor for the prestage AGC

Pin 12: DC-Voltage alters the threshold voltage of the prestage AGC-circuit.

Pin 13,14: Sym. input for the AM-Signal in the frequency range of 100 kHz to 160 MHz.

Pin 15: GROUND: All DC-Values are referred to this pin. All RF blocking capacitors should be

connected to this point.

Pin 16: Output for the internal reference voltage. This pin is to be blocked with

a ceramic capacitor to RF ground.

Pin17: Input for the frequency divider.

Pin 18: Buffered output for the oscillator frequency

Pin 19: Buffered output for the by n divided (n= 6 or 10) Oscillator frequency

Pin 20,21: The ext. LC-Circuit determines the oscillator frequency

Pin 22: Blocking capacitor for the IF-AGC-Circuit to suppress AF-frequencies

Pin 23: Buffered AF output

Pin 24,25,26: Input-Pins for the DC-coupeled AGC-Amplifier 1.

Pin 27: Buffered output for the AGC-controlled lower IF-Signal. This pin is connected

to the AM-Stereo-Decoder.

Pin 28: Input for the 2. Local oscillator (LO). The pin has to be forced

with an ext. signal

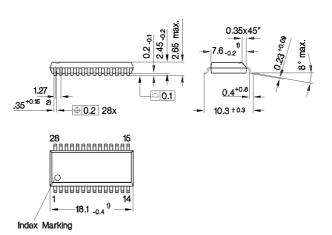
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Package Outline

Plastic Package P-DSO-28-1



- 1) Does not include plastic or metal protrusion of 0.15 max. per side
- 2) Does not include dambar protrusion

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Absolute Maximum Ratings

The maximal ratings may not be exceeded under any circumstances, not even momentarily and individually, as permanent damage to the IC will result.

#	Max. Ratings for ambient temperature T _{amb} -40°C to 85°C	Symbol	Min	Max	Units	Remarks
1	Supply voltage	V ₆	0	13.2	V	
2	Reference voltage	V ₁₆	0	5	V	
3	Reference current	I ₁₆	0	1	mA	
4	Prestage threshold	V ₁₂	0	5	V	
5	Mixer 1 input	V_{13}, V_{14}	0	5	V	
6	Logical divider input	V ₁₇	0	13.2	V	
7	Counter output	V ₁₈	0	13.2	V	
8	Divided counter output	V ₁₉	0	13.2	V	
9	1.LO	V_{20}, V_{21}	0	5	V	
10	Time constant for 2 IF AGC	V ₂₂	0	5	V	
11	Leakage current	l ₂₂		1	uA	
12	AF-output	V ₂₃	0	13.2	V	
14	AGC input	V_{24} , V_{25} , V_{26}	0	5	V	
15	AM-Stereo output	V ₂₇	0	13.2	V	
16	2. LO input	V ₂₈	0	5	V	
17	2. Mixer output	V _{1,2}	0	5	V	
18	2. Mixer input	V _{4,5}	0	5	V	
19	1. Mixer output	V _{7,8}	0	13.2	V	
20	AGC-Time	V ₉	0	13.2	V	
21	Prestage AGC	V ₁₀	0	13.2	V	
22	PrestageTime constante	V ₁₁	0	13.2	V	
23	ESD voltage	V_{ESD}	-2	+2	kV *)	
	human body model					
	100 pF/1500 Ω					
24	Thermal Resistance	R_{thSA}		76	k/W	

^{*) 2} kV ESD protection is not valid for pin 28

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Operational Range

Within the operational range the IC operates as described in the circuit description. The AC / DC characteristic limits are not guaranteed.

#	Parameter	Symbol	Min	Max	Units	Remarks
1	Supply Voltage	V_6	7.5	11	V	
2	Ambient temperature	T_{amb}	-40	+85	°C	

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AC/DC Characteristics

AC / DC characteristics involve the spread of values guaranteed within the specified supply voltage and ambient temperature range. Typical characteristics are the median of the production.

#	Parameter S	ymbol	Test Conditions	Test Circuit	Min	Тур	Max	Units
	ly voltage ent temperature		V _S =8.5V T _{amb} = 25 °C					
			f _{IF1} = 10.7 MHz f _{IF2} = 450 kHz f _i = 1 MHz					
1	Current consumption	1 l ₆ + l ₁ +l ₂ + l ₇ +l ₈	n=10	1	50	62	77	mA
Mixer 2	Interceptpoint	IP3	V ₁₃ -V ₁₄	Lab		130		dBuV
3 4 5	3. Order Mixer gain Max. input voltage Noise figure (10 MHz		20 lg V ₅ / V ₁₃ -V ₁₄ ₄ for -1 dB compression	1 1 Lab	0	2	4 600 10	dB mV _{pp} dB
1. LO 6 7 8 9 10	Frequency range Counter output Divided counter outp Output impedance Output impedance	f _{1.LO} V ₁₈ ut V ₁₉ R _{ex18} R _{ex19}	R_L =330 Ω R_L =330 Ω	Lab 1 1 Lab Lab	60 70 35	100 50 330 330	160	$\begin{array}{c} \text{MHz} \\ \text{mV}_{\text{rms}} \\ \text{mV}_{\text{rms}} \\ \Omega \\ \Omega \end{array}$
<u>Conv</u> 11 12	<u>erter</u> Mixer gain Noise figure	V F		1 Lab	2	5	8 10	dB dB
2. LO 13 14	Frequency range External force voltag	f _{2.LO} e V ₂₈		1	25 60			MHz mV _{rms}
Prest 15 16 17 18	age AGC output AGC-Voltage AGC-Voltage Integrator current Integrator current	U ₁₀ U ₁₀ I ₁₁ * I ₁₁ *	V ₁₃ -V ₁₄ =0mV _{rms} V ₁₃ -V ₁₄ =400mV _{rms} V ₁₃ -V ₁₄ =0mV _{rms} V ₁₃ -V ₁₄ =200mV _{rms}	1 1 1	6.3	7.2 0.7 -30 30	V _S 1	V V uA uA

^{*)} integrator currents are measured between the output pin (- Pole of the measurement equipment) and a voltage source with a value of 3V_{DC} (+ Pole).

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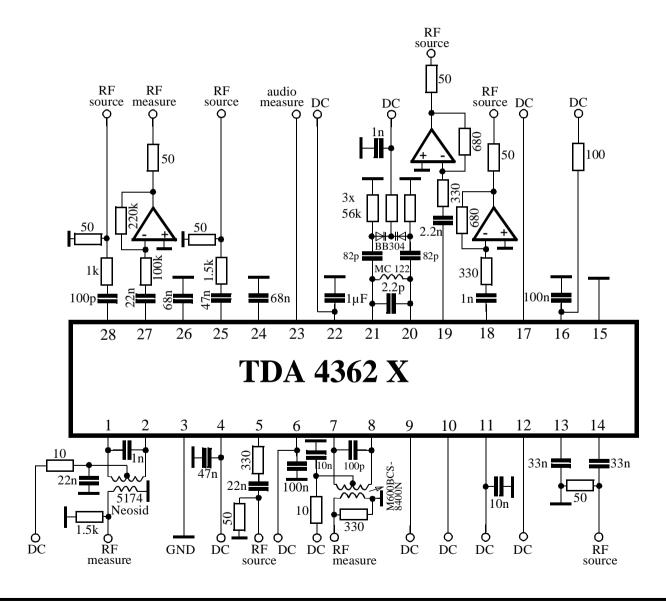
#	Parameter	Symbol	Test Conditions	Test Circuit	Min	Тур	Max	Units
<u>AGC</u>	-Amplifier		$V_i = V_{25} - V_{26} $					
19	AGC-Range			1	60	66		dB
20	AGC-Voltage	V_{22}	V _i =0 mV _{rms}	1		0.6	1	V
21	AGC-Voltage	V ₂₂	V_i =500 μV_{rms}	1	1.1	1.45	1.8	V
22	AGC-Voltage	V ₂₂	V _i =30 mV _{rms}	1	2.7	3.1	3.7	٧,,
23	reg. output voltage	V ₂₇	$R_L=100k\Omega$	1	48	60		mV _{rms}
24 25	Input sensitivity AGC-current	V _i	V _{23 100mV} - 3dB	1 fact 1	400	100 500	650	μ V_{rms} μ Α
26	AGC-current	l ₂₂ l ₂₂	V _i =100mV _{rms} AGC= V _i = 0mV _{rms} AGC=1	fast 1	-400	-500	-650	μ Α μ Α
27	AGC-current	l ₂₂	V _i =100mV _{rms} AGC=		15	25	35	μ Α
28	AGC-current	l ₂₂	V _i = 0mV _{rms} AGC=	slow 1	-13	-25	-33	μ Α
AM-E	<u>Demodulator</u>		$V_{i} = V_{25} - V_{26} $					
29	AF output voltage	V_{23}	m=0.3	Lab		180		mV_{rms}
30	AF output voltage	V_{23}	m=0.8	1	400	480	560	mV_{rms}
31	Total harm. distortion		$V_i = 10 \text{ mV}_{rms}, m = 0.$			1	1.7	%
32	Input voltage for S+N/N=6 dB	V _i	m=0.3	Lab	10			μ V $_{rms}$
33	Input voltage for S+N/N=26 dB	V _i	m=0.3	Lab	100			μV_{rms}
34	S+N/N		$V_i = 10 \text{ mV}, m = 0.8$	1	58	64		dB
35	AF-Linearity	ΔV_{23}	100μV/100 mV	1			3	dB
Divid	ler Ratio							
36	Input voltage "L"	V ₁₇	divide by 10	1	0		1.5	V
37	Input voltage "H"	V ₁₇	divide by 6	1	3.0		V _S	v
	-Times	''	·				3	
38	Fast	V ₉		1	2.0		V_s	V
39	Slow	V_9		1	0		0.7	V
Refe	rence voltage							
40	Reference voltage	V ₁₆		1	4.5	4.8	5.1	V

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Test Circuit



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Application Circuit

AM dual conversion receiver

